











OPA4277-EP

SBOS714-NOVEMBER 2014

OPA4277-EP High Precision Operational Amplifier

Features

Ultra-Low Offset Voltage: 10 µV Ultra-Low Drift: ±0.1 µV/°C

High Open-Loop Gain: 134 dB

High Common-Mode Rejection: 140 dB High-Power Supply Rejection: 130 dB

Low Bias Current: 1-nA Max Wide Supply Range: ±2 to ±18 V

Low Quiescent Current: 800 µA/Amplifier

Supports Defense, Aerospace, and Medical **Applications**

Controlled Baseline

One Assembly and Test Site

One Fabrication Site

 Available in Military (–55°C to 125°C) Temperature Range

Extended Product Life Cycle

Extended Product-Change Notification

Product Traceability

2 Applications

Transducer Amplifier

Bridge Amplifier

Temperature Measurements

Strain Gage Amplifier

Precision Integrator

Battery Powered Instruments

Test Equipment

3 Description

The OPA4277-EP precision operational amplifier replaces the industry standard OP-177. It offers improved noise, wider output voltage swing, and is twice as fast with half the quiescent current. Features include ultra-low offset voltage and drift, low bias current, high common-mode rejection, and high power supply rejection.

The OPA4277-EP operates from ±2- to ±18-V supplies with excellent performance. Unlike most operational amplifiers which are specified at only one vlqque voltage. the OPA4277-EP operational amplifier is specified for real-world applications; a single limit applies over the ±5- to ±15-V supply range. High performance is maintained as the amplifier swings to the specified limits. Because the initial offset voltage (±20-µV max) is so low, user adjustment is usually not required.

The OPA4277-EP is easy to use and free from phase inversion and overload problems found in some operational amplifiers. It is stable in unity gain and provides excellent dynamic behavior over a wide range of load conditions. The OPA4277-EP features completely independent circuitry for lowest crosstalk and freedom from interaction, even when overdriven or overloaded.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
OPA4277MDTEP	SOIC (14)	3.91 mm × 8.65 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

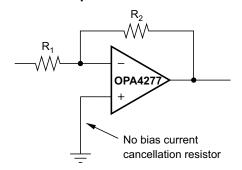






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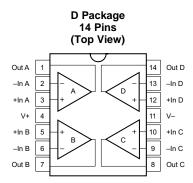
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4 Revision History

DATE	REVISION	NOTES
November 2014	*	Initial release.



5 Pin Configuration and Functions



Pin Functions

Р	IN	1/0	DECORPORTION			
NAME	NO.	1/0	DESCRIPTION			
OUT A	1	0	Amplifier output A			
−IN A	2	I	Inverting amplifier input A			
+IN A	3	I	oninverting amplifier input A			
V+	4	Р	ositive amplifier power supply input			
+IN B	5	I	Noninverting amplifier input B			
–IN B	6	I	Inverting amplifier input B			
OUT B	7	0	Amplifier output B			
OUT C	8	0	Amplifier output C			
–IN C	9	I	Inverting amplifier input C			
+IN C	10	I	Noninverting amplifier input C			
V-	11	Р	Negative amplifier power supply input			
+IN D	12	I	Noninverting amplifier input D			
–IN D	13	I	Inverting amplifier input D			
OUT D	14	0	Amplifier output D			

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted) (1)

	MIN	MAX	UNIT
Supply voltage		36	V
Input voltage	(V-) - 0	.7 (V+) + 0.7	V
Output short circuit	С	Continuous	
Operating temperature	-55	125	°C
Junction temperature		150	°C
Lead temperature (soldering, 10 s)		300	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature	range	- 55	125	°C
V	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	-2000	2000	\/
V _(ESD)	discharge	Machine model (MM)	-100	100	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Dual supply voltage	±5	±15	V
T _J Operating junction temperature	-55	125	°C

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	OPA4277-EP	LIMIT
	THERMAL METRIC**	D (14 PINS)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	66.3	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	19.3	
$R_{\theta JB}$	Junction-to-board thermal resistance	26.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	2.1	C/VV
ΨЈВ	Junction-to-board characterization parameter	26.2	
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics

At T_J = 25°C, and R_L = 2 k Ω , V_S = ±5 to ±15 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFFSET \	VOLTAGE						
V	Input offset voltage			±20	±65	\/	
V _{OS}	Input offset voltage over temperature	T _J = -55°C to 125°C			±140	μV	
dV _{OS} /d _T	Input offset voltage drift			±0.15		μV/°C	
		vs time		0.2		μV/mo	
PSRR	Input offset voltage	vs power supply, $V_S = \pm 2$ to ± 18 V		±0.3	±1	μV/V	
TOTAL	input onest rollage	$T_J = -55^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}; V_S = \pm 2 \text{ to}$ $\pm 18 \text{ V}$			±1	μV/V	
	Channel separation	dc		0.1		μV/V	
INPUT BIA	AS CURRENT	,					
I_	Input bias current			±0.5	±2.8	nA	
I _B	input bias current	$T_J = -55$ °C to 125°C			±7.5	ПД	
laa	Input offset current			±0.5	±2.8	nA	
los	input onset current	$T_J = -55$ °C to 125°C			±7.5	ПА	
NOISE		,					
	Input voltage noise	f = 0.1 to 10 Hz		0.22		μV_{pp}	
		f = 10 Hz		12			
	Input voltage noise density	f = 100 Hz		8		nV/√ Hz	
e _n	input voltage hoise density	f = 1 kHz		8			
		f = 10 kHz		8			
in	Current noise density	f = 1 kHz		0.2		pA/√ Hz	
INPUT VO	DLTAGE	,					
V_{CM}	Common-mode voltage range		(V-) + 2		(V+) - 2	V	
		$V_{CM} = (V-) + 2 V \text{ to } (V+) - 2 V$	115	140			
CMRR	Common-mode rejection	$T_J = -55^{\circ}\text{C to } 125^{\circ}\text{C}; V_{CM} = (V-) + 2$ V to $(V+) - 2$ V	115			dB	
INPUT IM	PEDANCE						
	Differential			100 3		$M\Omega \parallel pF$	
	Common mode	V _{CM} = (V-) + 2 V to (V+) - 2 V		250 3		$G\Omega \parallel pF$	
OPEN-LO	OP GAIN						
		$V_O = (V-) + 0.5 \text{ V to } (V+) - 1.2 \text{ V},$ $R_L = 10 \text{ k}\Omega$		140			
A _{OL}	Open-loop voltage gain	$V_O = (V-) + 1.5 \text{ V to } (V+) - 1.5 \text{ V},$ $R_L = 2 \text{ k}\Omega$	126	134		dB	
		$T_J = -55^{\circ}\text{C to } 125^{\circ}\text{C}; V_O = (V-) + 1.5 \text{ V to } (V+) - 1.5 \text{ V}, R_L = 2 \text{ k}\Omega$	126				
FREQUEN	NCY RESPONSE						
GBW	Gain-bandwidth product			1		MHz	
SR	Slew rate			0.8		V/µs	
	Cotting time	0.1%, V _S = ±15 V, G = 1, 10-V step		14			
	Setting time	0.01%, V _S = ±15 V, G = 1, 10-V step		16		μs	
THD + N	Total harmonic distortion + noise	1 kHz, G = 1, V _O = 3.5 Vrms		0.002%			

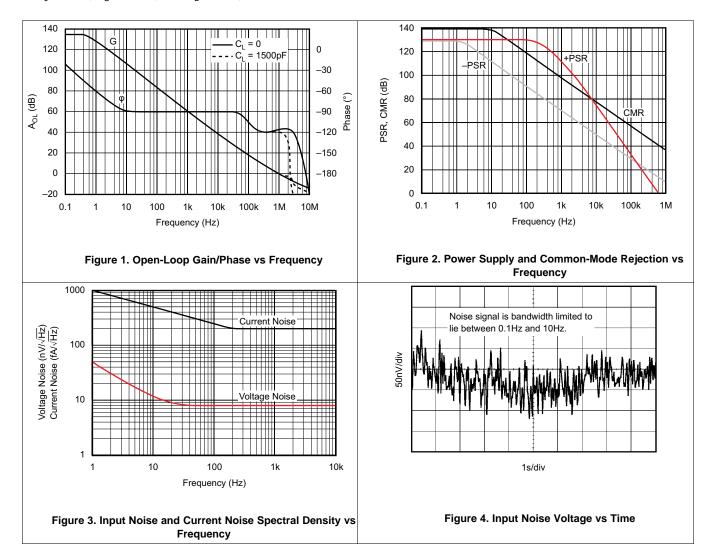
Electrical Characteristics (continued)

At $T_J = 25$ °C, and $R_L = 2 \text{ k}\Omega$, $V_S = \pm 5 \text{ to } \pm 15 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
OUTPUT					
V _O Voltage output		$T_J = -55$ °C to 125°C; $R_L = 10 \text{ k}\Omega$	(V-) + 0.5	(V+) - 1.2	V
Vo	voltage output	$T_J = -55$ °C to 125°C; $R_L = 2 \text{ k}\Omega$	(V-) + 1.5	(V+) - 1.5	
I _{SC}	Short-circuit current			±35	mA
C_{LOAD}	Capacitive load drive		See Typica	al Characteristics	
POWER	SUPPLY				
Vs	Specified voltage		±5	±15	V
	Operating voltage		±2	±18	V
	Quincont ourrent (nor amplifier)	I _O = 0		±790 ±825	
IQ	Quiescent current (per amplifier)	$T_J = -55^{\circ}C$ to 125°C; $I_O = 0$		±900	μΑ

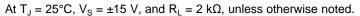
6.6 Typical Characteristics

At T_J = 25°C, V_S = ±15 V, and R_L = 2 $k\Omega,$ unless otherwise noted.





Typical Characteristics (continued)



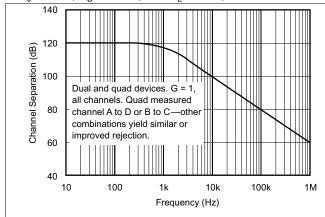


Figure 5. Channel Separation vs Frequency

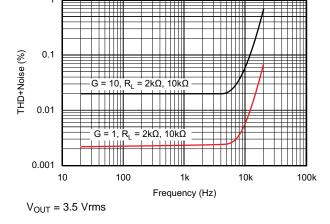


Figure 6. Total Harmonic Distortion + Noise vs Frequency

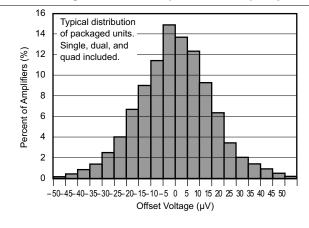


Figure 7. Offset Voltage Production Distribution

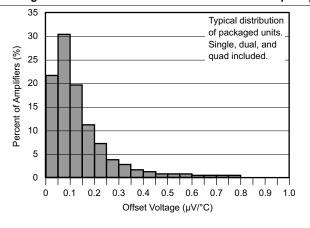
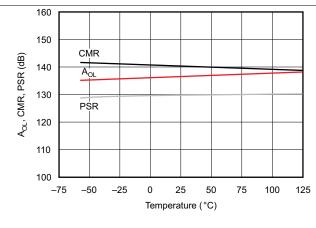
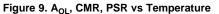


Figure 8. Offset Voltage Drift Production Distribution





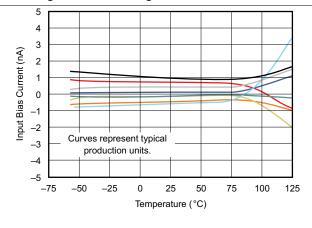
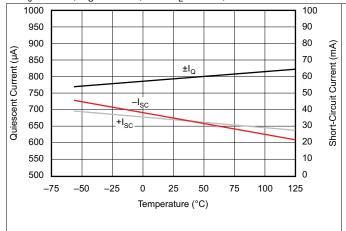


Figure 10. Input Bias Current vs Temperature

Typical Characteristics (continued)

At $T_J = 25$ °C, $V_S = \pm 15$ V, and $R_L = 2$ k Ω , unless otherwise noted.



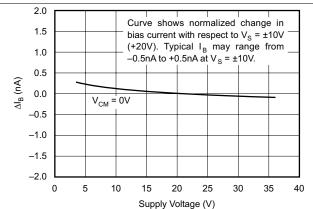
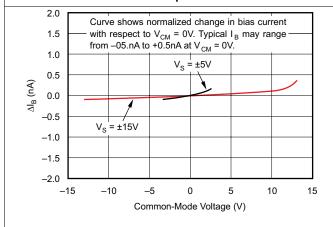


Figure 11. Quiescent Current and Short-Circuit Current vs
Temperature

Figure 12. Change in Input Bias Current vs Power Supply Voltage



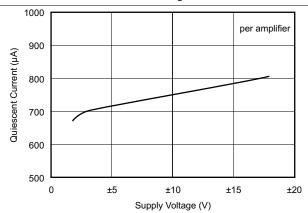
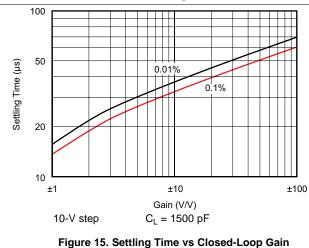


Figure 13. Change in Input Bias Current vs Common-Mode Voltage

Figure 14. Quiescent Current vs Supply Voltage



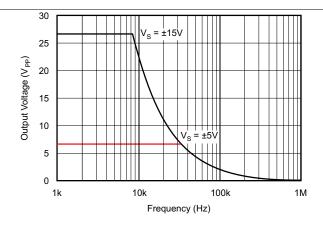
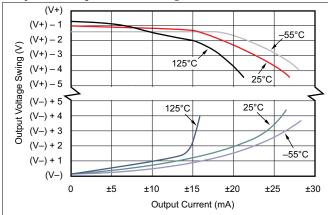


Figure 16. Maximum Output Voltage vs Frequency



Typical Characteristics (continued)

At $T_J = 25$ °C, $V_S = \pm 15$ V, and $R_L = 2$ k Ω , unless otherwise noted.



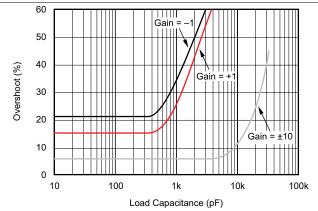
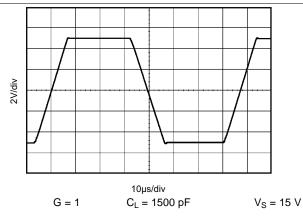


Figure 17. Output Voltage Swing vs Output Current

Figure 18. Small-Signal Overshoot vs Load Capacitance



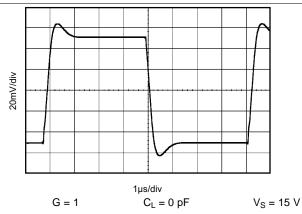


Figure 19. Large-Signal Step Response

Figure 20. Small-Signal Step Response

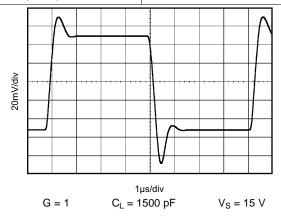


Figure 21. Small-Signal Step Response

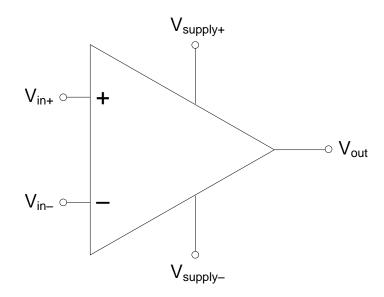
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7 Detailed Description

7.1 Overview

The OPA4277-EP precision operational amplifier replaces the industry standard OP-177. It offers improved noise, wider output voltage swing, and is twice as fast with half the quiescent current. Features include ultra-low offset voltage and drift, low bias current, high common-mode rejection, and high power supply rejection.

7.2 Functional Block Diagram



7.3 Feature Description

The OPA4277-EP operates from ± 2 - to ± 18 -V supplies with excellent performance. Unlike most operational amplifiers which are specified at only one supply voltage, the OPA4277-EP precision operational amplifier is specified for real-world applications; a single limit applies over the ± 5 - to ± 15 -V supply range. High performance is maintained as the amplifier swings to the specified limits. Because the initial offset voltage ($\pm 50~\mu V$ max) is so low, user adjustment is usually not required.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA4277 is unity-gain stable and free from unexpected output phase reversal, making it easy to use in a wide range of applications. Applications with noisy or high-impedance power supplies may require decoupling capacitors close to the device pins. In most cases, 0.1-µF capacitors are adequate.

8.2 Typical Application

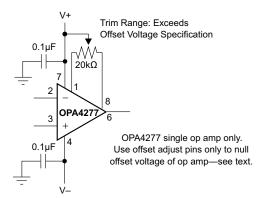


Figure 22. OPA4277 Offset Voltage Trim Circuit

8.2.1 Design Requirements

For the thermocouple low-offset, low-drift loop measurement with diode cold junction compensation (see Figure 25), Table 1 lists the design parameters needed with gain = 50.

$$G = 1 + \frac{2R_F}{R} = 50 \tag{1}$$

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE		
R _F	10 kΩ		
R	412 Ω		

8.2.2 Detailed Design Procedure

8.2.2.1 Offset Voltage Adjustment

The OPA27 is laser-trimmed for very-low offset voltage and drift so most circuits do not require external adjustment. However, offset voltage trim connections are provided on pins 1 and 8. The user can adjust offset voltage by connecting a potentiometer as shown in Figure 22. Only use this adjustment to null the offset of the operational amplifier. This adjustment should not be used to compensate for offsets created elsewhere in a system because this can introduce additional temperature drift.

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8.2.2.2 Input Protection

The inputs of the OPA4277 are protected with $1-k\Omega$ series input resistors and diode clamps. The inputs can withstand ± 30 -V differential inputs without damage. The protection diodes conduct current when the inputs are overdriven. This may disturb the slewing behavior of unity-gain follower applications, but will not damage the operational amplifier.

8.2.2.3 Input Bias Current Cancellation

The input stage base current of the OPA4277 is internally compensated with an equal and opposite cancellation circuit. The resulting input bias current is the difference between the input stage base current and the cancellation current. This residual input bias current can be positive or negative.

When the bias current is canceled in this manner, the input bias current and input offset current are approximately the same magnitude. As a result, it is not necessary to use a bias current cancellation resistor, as is often done with other operational amplifiers (see Figure 23). A resistor added to cancel input bias current errors may actually increase offset voltage and noise.

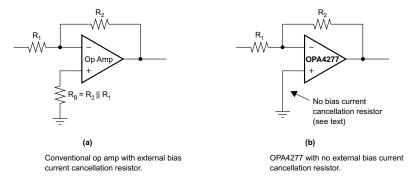
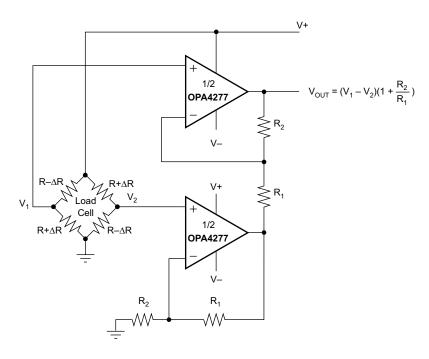


Figure 23. Input Bias Current Cancellation



For integrated solution see: INA126, INA2126 (dual)
INA125 (on-board reference)
INA122 (single-supply)

Figure 24. Load Cell Amplifier

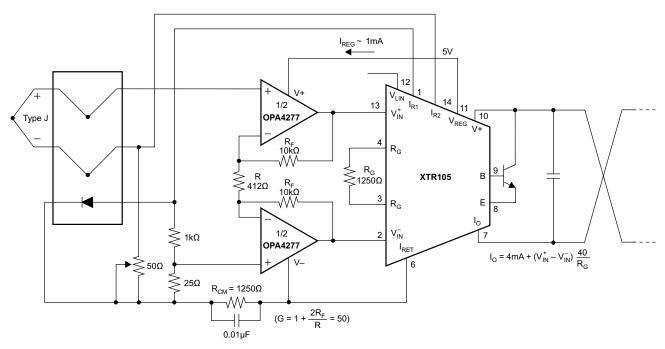


Figure 25. Thermocouple Low Offset, Low Drift Loop Measurement With Diode Cold Junction Compensation

8.2.3 Application Curve

At $T_J = 25$ °C, $V_S = \pm 15$ V, and $R_L = 2$ k Ω , unless otherwise noted.

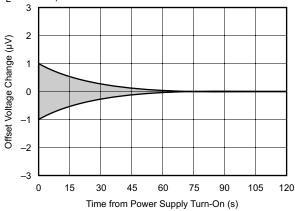


Figure 26. Warm-Up Offset Voltage Drift

9 Power Supply Recommendations

OPA4277 operates from ± 2 - to ± 18 -V supplies with excellent performance. Unlike most operational amplifiers which are specified at only one supply voltage, the OPA4277 is specified for real-world applications; a single limit applies over the ± 5 - to ± 15 -V supply range. This allows a customer operating at $V_S = \pm 10$ V to have the same assured performance as a customer using ± 15 -V supplies. In addition, key parameters are assured over the specified temperature range, -55°C to 125°C. Most behavior remains unchanged through the full operating voltage range (± 2 to ± 18 V). Parameters which vary significantly with operating voltage or temperature are shown in the typical performance curves.

10 Layout

10.1 Layout Guidelines

The leadframe die pad should be soldered to a thermal pad on the PCB. Mechanical drawings located in *Mechanical, Packaging, and Orderable Information* show the physical dimensions for the package and pad.

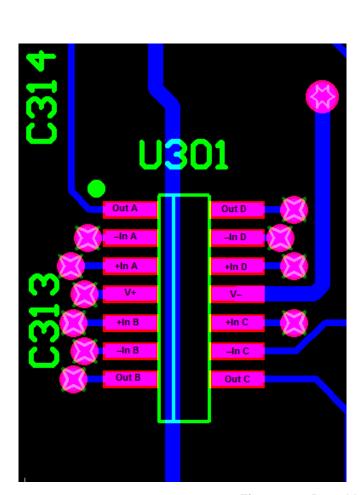
Soldering the exposed pad significantly improves board-level reliability during temperature cycling, key push, package shear, and similar board-level tests. Even with applications that have low-power dissipation, the exposed pad must be soldered to the PCB to provide structural integrity and long-term reliability.

The OPA4277 has very-low offset voltage and drift. To achieve highest performance, optimize circuit layout and mechanical conditions. Offset voltage and drift can be degraded by small thermoelectric potentials at the operational amplifier inputs. Connections of dissimilar metals generate thermal potential, which can degrade the ultimate performance of the OPA4277. Cancel these thermal potentials by assuring that they are equal in both input terminals.

- Keep the thermal mass of the connections made to the two input terminals similar.
- Locate heat sources as far as possible from the critical input circuitry.
- Shield operational amplifier and input circuitry from air currents such as cooling fans.



10.2 Layout Example



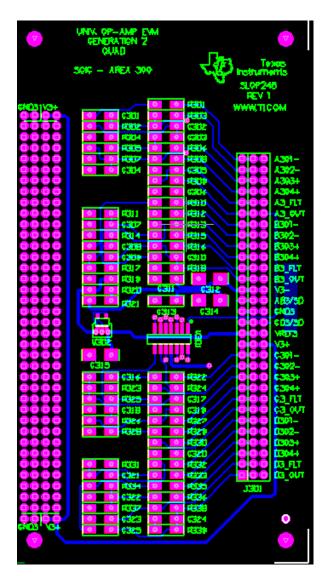


Figure 27. Board Layout Example

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11 Device and Documentation Support

11.1 Trademarks

All trademarks are the property of their respective owners.

11.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
OPA4277MDTEP	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAUAG	Level-3-260C-168 HR	-55 to 125	OPA4277EP
OPA4277MDTEP.A	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAUAG	Level-3-260C-168 HR	-55 to 125	OPA4277EP

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF OPA4277-EP:

Catalog: OPA4277

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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• Space : OPA4277-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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